

# **DATASHEET**

# 4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER **EL817 Series**



#### Features:

- Current transfer ratio (CTR:  $50\sim600\%$  at IF = 5mA, VcE = 5V)
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- •The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No.E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

## **Description**

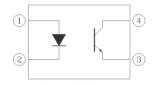
The EL817 series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

# **Applications**

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

#### **Schematic**



#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

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# Absolute Maximum Ratings (Ta=25℃)

Parameter	Symbol	Rating	Unit
Forward current	I <sub>F</sub>	60	mA
Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Reverse voltage	V <sub>R</sub>	6	V
Power dissipation	Р	100	mW
Derating factor (above T <sub>a</sub> = 100°C)	$P_{D}$	2.9	mW/°C
Power dissipation		150	mW
Derating factor (above T <sub>a</sub> = 100°C)	P <sub>C</sub>	5.8	mW/°C
Collector current	I <sub>C</sub>	50	mA
Collector-Emitter voltage	V <sub>CEO</sub>	35	V
Emitter-Collector voltage	V <sub>ECO</sub> 6		V
Dissipation	P <sub>TOT</sub>	200	mW
Isolation Voltage*1		5000	V rms
mperature	T <sub>OPR</sub>	-55 to 110	°C
perature	T <sub>STG</sub>	-55 to 125	°C
Soldering Temperature* <sup>2</sup>		260	°C
֡	Forward current  Peak forward current (1us, pulse)  Reverse voltage  Power dissipation Derating factor (above T <sub>a</sub> = 100°C)  Power dissipation Derating factor (above T <sub>a</sub> = 100°C)  Collector current  Collector-Emitter voltage  Emitter-Collector voltage  Dissipation  tage*  Imperature  perature	Forward current $I_F$ Peak forward current (1us, pulse) $I_{FP}$ Reverse voltage $V_R$ Power dissipation $P_D$ Derating factor (above $T_a = 100^{\circ}C$ )  Power dissipation $P_C$ Collector current $I_C$ Collector-Emitter voltage $V_{CEO}$ Emitter-Collector voltage $V_{CEO}$ Dissipation $P_{TOT}$ tage*1 $V_{ISO}$ mperature $T_{STG}$	Forward current $I_F$ 60  Peak forward current (1us, pulse) $I_{FP}$ 1  Reverse voltage $V_R$ 6  Power dissipation Derating factor (above $T_a$ = 100°C) $P_D$ 2.9  Power dissipation Derating factor (above $T_a$ = 100°C) $P_C$ 5.8  Collector current $I_C$ 50  Collector-Emitter voltage $I_C$ 7  Emitter-Collector voltage $I_C$ 7  Dissipation $I_C$ 7  Dissipation $I_C$ 7  Prot 200  Eage*1 $I_C$ 7  Emitter-Collector voltage $I_C$ 8  Emi

#### Notes:

狀態:Approved(止式發行)

<sup>\*1</sup> AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

<sup>\*2</sup> For 10 seconds



# Electro-Optical Characteristics (Ta=25℃ unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	$V_{F}$	-	1.2	1.4	V	I <sub>F</sub> = 20mA
Reverse Current	I <sub>R</sub>	-	-	10	μA	V <sub>R</sub> = 4V
Input capacitance	C <sub>in</sub>	-	30	250	pF	V = 0, f = 1kHz

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition	
Collector-Emitter dark	loso	_	_	100	nA	$V_{CE} = 20V, I_{F} = 0mA$	
current	ICEO			100	117 (	VGE 20V, IF OIII/	
Collector-Emitter	$BV_CEO$	35	_	_	V	$I_{C} = 0.1 \text{mA}$	
breakdown voltage	D A CEO	00	_		•	1C - 0. 1111/4	
Emitter-Collector	D\/	6	-		V	$I_E = 0.1 \text{mA}$	
breakdown voltage	$BV_{ECO}$	0		-	V		

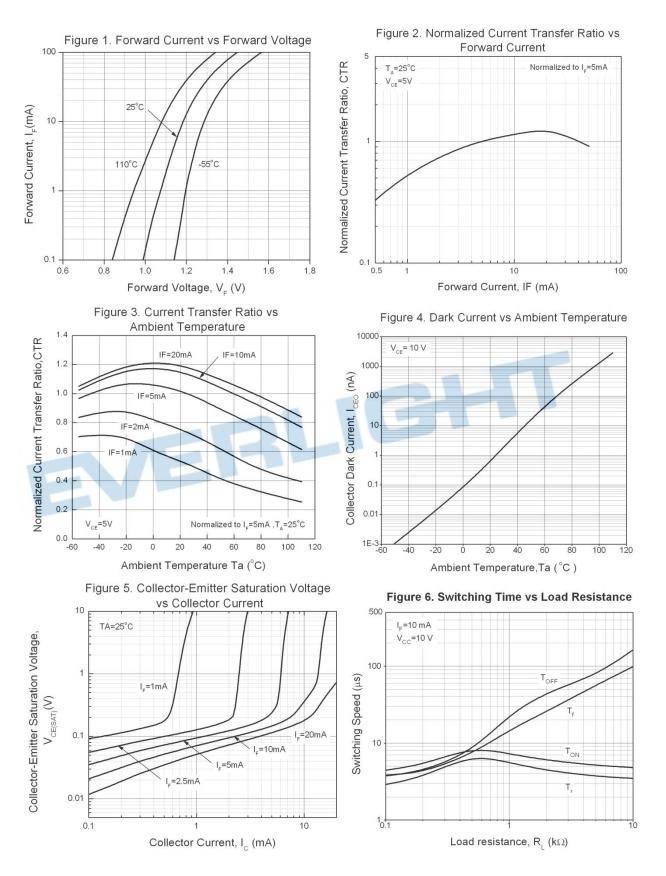
**Transfer Characteristics** 

Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition
	EL817	Æ	50		600		I <sub>F</sub> = 5mA ,V <sub>CE</sub> = 5V
	EL817A		80	_	160	- - - % -	
Current	EL817B		130	-	260		
Transfer	EL817C	CTR	200	-	400		
ratio	EL817D		300	-	600		
	EL817X		100	-	200		
	EL817Y		150	-	300		
Collector-E saturation		$V_{\text{CE(sat)}}$	-	0.1	0.2	V	$I_F = 20 \text{mA}, I_C = 1 \text{mA}$
Isolation re	esistance	R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.
Floating ca	apacitance	$C_{IO}$	-	0.6	1.0	pF	$V_{IO} = 0$ , $f = 1MHz$
Cut-off free	quency	fc	-	80	-	kHz	$V_{CE} = 5V, I_{C} = 2mA$ $R_{L} = 100\Omega, -3dB$
Rise time		$t_r$	-	-	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time		t <sub>f</sub>	-	-	18	μs	$R_L = 100\Omega$

<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C



## **Typical Electro-Optical Characteristics Curves**



狀態:Approved(止式發行)



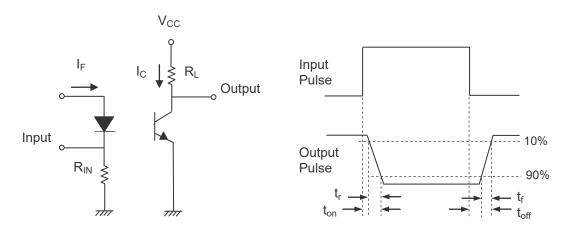


Figure 7. Switching Time Test Circuit & Waveforms



Release Date: 11/10/2016



#### **Order Information**

#### **Part Number**

# **EL817X(Y)(Z)-FV**

#### Note

X = Lead form option (S, S1, S2, M or none)

Y = CTR Rank (A, B, C, D, X, Y or none)

Z = Tape and reel option (TU, TD or none)

F = Lead frame option (F: Iron, None: copper)

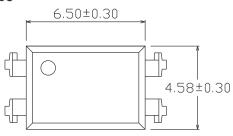
V = VDE safety (optional)

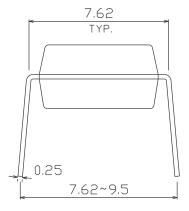
Option	Description	Packing quantity	
None	Standard DIP-4	100 units per tube	
M	Wide lead bend (0.4 inch spacing)	100 units per tube	
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel	
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel	
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel	
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel	
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel	
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel	

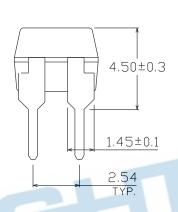


# Package Dimension (Dimensions in mm)

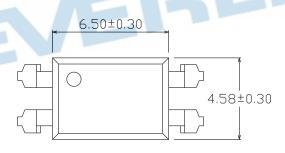
## **Standard DIP Type**

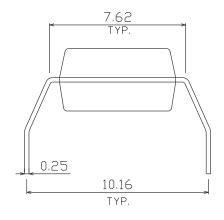


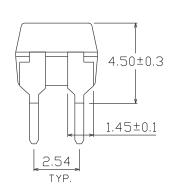




# **Option M Type**

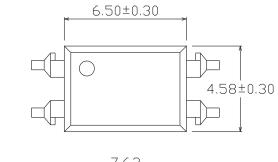


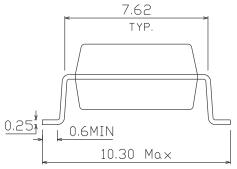


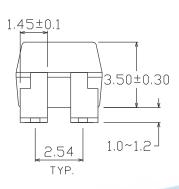




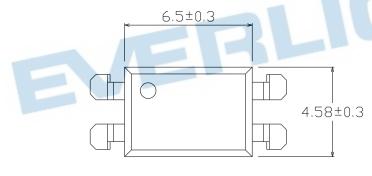
## **Option S Type**

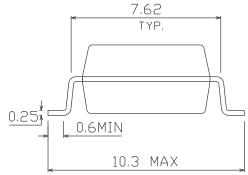


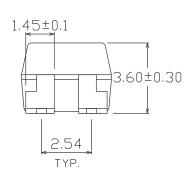




## **Option S1 Type**

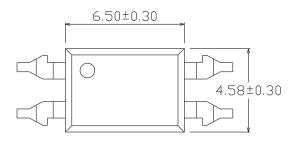


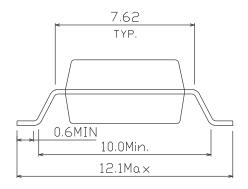


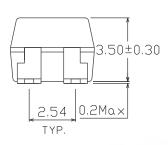




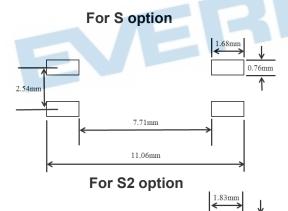
## **Option S2 Type**

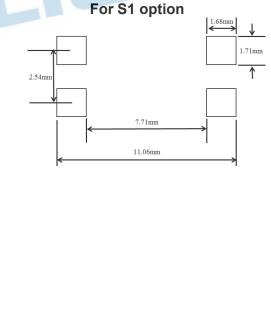






# Recommended pad layout for surface mount leadform





狀態:Approved(止式發行)



2.54mi

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

9.21mm

12.86mm



## **Device Marking**



#### **Notes**

EL	denotes EVERLIGHT
817	denotes Device Number

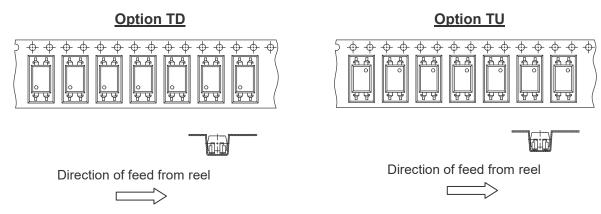
F denotes Factory Code (G: China and Green part) R denotes CTR Rank (A, B, C, D , X , Y or none)

Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)

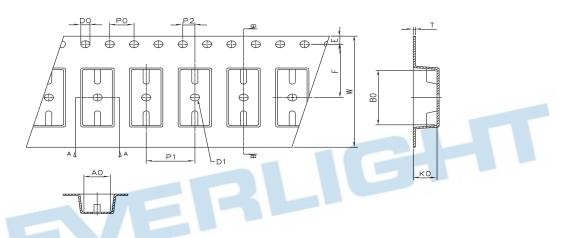




**Tape & Reel Packing Specifications** 



# **Tape dimensions**



Dimension No.	Ao	Во	Do	D1	E	F
Dimension (mm) S.S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ko
Dimension (mm) S.S1	4.00±0.1	8.00±0.1	2.00±0.1	0.40±0.1	16.00±0.3	4.60±0.1
Dimension (mm) S2	4.00±0.1	8.00±0.1	2.00±0.1	0.40±0.1	24.00±0.3	4.00±0.1

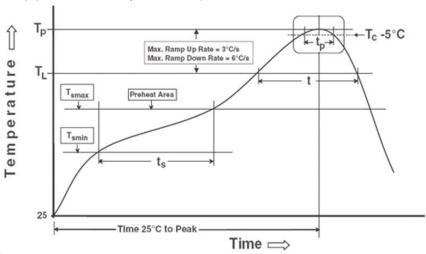
狀態:Approved(正式發行)



#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

#### **Preheat**

Temperature min (T<sub>smin</sub>)

Temperature max (T<sub>smax</sub>)

Time (Tsmin to Tsmax) (ts)

Average ramp-up rate (Tsmax to Tp)

#### Other

Liquidus Temperature (T<sub>L</sub>)

Time above Liquidus Temperature (t L)

Peak Temperature (T<sub>P</sub>)

Time within 5 °C of Actual Peak Temperature: T<sub>P</sub> - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C

200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times

狀態:Approved(止式發行)



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